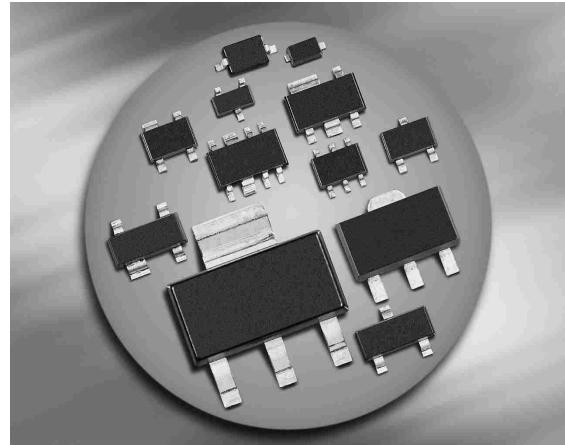


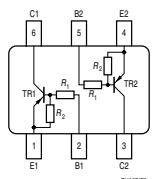
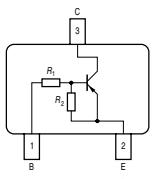
### PNP Silicon Digital Transistor

- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ( $R_1 = 10\text{k}\Omega$ ,  $R_2 = 47\text{k}\Omega$ )
- For 6-PIN packages: two (galvanic) internal isolated transistors with good matching in one package



**BCR185/F/L3**  
**BCR185T/W**

**BCR185S/U**  
**SEMB9**



Type	Marking	Pin Configuration							Package
BCR185	WNs	1=B	2=E	3=C	-	-	-	-	SOT23
BCR185F	WNs	1=B	2=E	3=C	-	-	-	-	TSFP-3
BCR185L3	WN	1=B	2=E	3=C	-	-	-	-	TSLP-3-4
BCR185S	WNs	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	-	SOT363
BCR185T	WNs	1=B	2=E	3=C	-	-	-	-	SC75
BCR185U	WNs	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	-	SC74
BCR185W	WNs	1=B	2=E	3=C	-	-	-	-	SOT323
SEMB9	WN	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	-	SOT666

**Maximum Ratings**

Parameter	Symbol	Value	Unit
Collector-emitter voltage	$V_{CEO}$	50	V
Collector-base voltage	$V_{CBO}$	50	
Emitter-base voltage	$V_{EBO}$	6	
Input on voltage	$V_{i(on)}$	20	
Collector current	$I_C$	100	mA
Total power dissipation- BCR185 $T_S \leq 102^\circ\text{C}$ BCR185F, $T_S \leq 128^\circ\text{C}$ BCR185L3, $T_S \leq 135^\circ\text{C}$ BCR185S, $T_S \leq 115^\circ\text{C}$ BCR185T, $T_S \leq 109^\circ\text{C}$ BCR185U, $T_S \leq 118^\circ\text{C}$ BCR185W, $T_S \leq 124^\circ\text{C}$ SEMB9, $T_S \leq 75^\circ\text{C}$	$P_{tot}$	200 250 250 250 250 250 250 250 250	mW
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-65 ... 150	

**Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup> BCR185 BCR185F BCR185L3 BCR185S BCR185T BCR185U BCR185W SEMB9	$R_{thJS}$	$\leq 240$ $\leq 90$ $\leq 60$ $\leq 140$ $\leq 165$ $\leq 133$ $\leq 105$ $\leq 300$	K/W

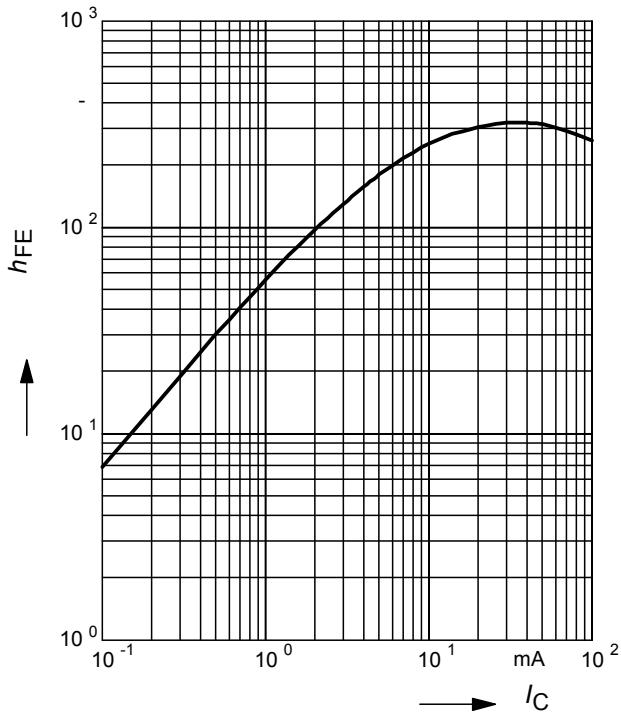
<sup>1)</sup>For calculation of  $R_{thJA}$  please refer to Application Note Thermal Resistance

**Electrical Characteristics at  $T_A = 25^\circ\text{C}$ , unless otherwise specified**

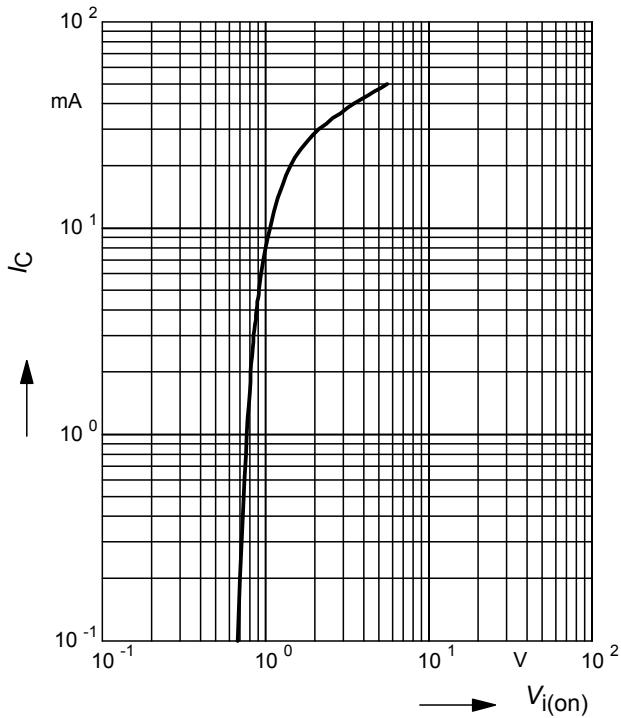
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
<b>DC Characteristics</b>					
Collector-emitter breakdown voltage $I_C = 100 \mu\text{A}, I_B = 0$	$V_{(\text{BR})\text{CEO}}$	50	-	-	V
Collector-base breakdown voltage $I_C = 10 \mu\text{A}, I_E = 0$	$V_{(\text{BR})\text{CBO}}$	50	-	-	
Collector-base cutoff current $V_{CB} = 40 \text{ V}, I_E = 0$	$I_{\text{CBO}}$	-	-	100	nA
Emitter-base cutoff current $V_{EB} = 6 \text{ V}, I_C = 0$	$I_{\text{EBO}}$	-	-	167	$\mu\text{A}$
DC current gain <sup>1)</sup> $I_C = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	$h_{\text{FE}}$	70	-	-	-
Collector-emitter saturation voltage <sup>1)</sup> $I_C = 10 \text{ mA}, I_B = 0,5 \text{ mA}$	$V_{\text{CEsat}}$	-	-	0,3	V
Input off voltage $I_C = 100 \mu\text{A}, V_{CE} = 5 \text{ V}$	$V_{i(\text{off})}$	0,5	-	1	
Input on voltage $I_C = 2 \text{ mA}, V_{CE} = 0,3 \text{ V}$	$V_{i(\text{on})}$	0,5	-	1,4	
Input resistor	$R_1$	7	10	13	k $\Omega$
Resistor ratio	$R_1/R_2$	0,19	0,21	0,24	-
<b>AC Characteristics</b>					
Transition frequency $I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}, f = 100 \text{ MHz}$	$f_T$	-	200	-	MHz
Collector-base capacitance $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$	$C_{cb}$	-	3	-	pF

<sup>1</sup>Pulse test:  $t < 300\mu\text{s}$ ;  $D < 2\%$

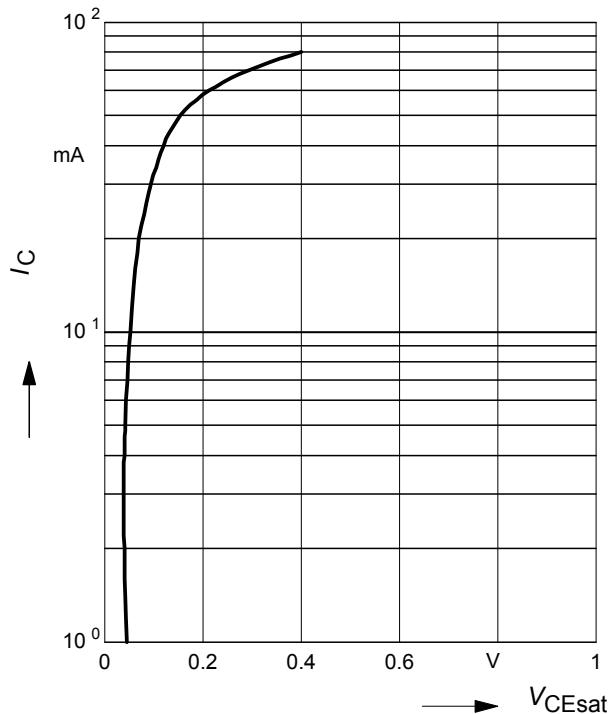
**DC current gain**  $h_{FE} = f(I_C)$   
 $V_{CE} = 5 \text{ V}$  (common emitter configuration)



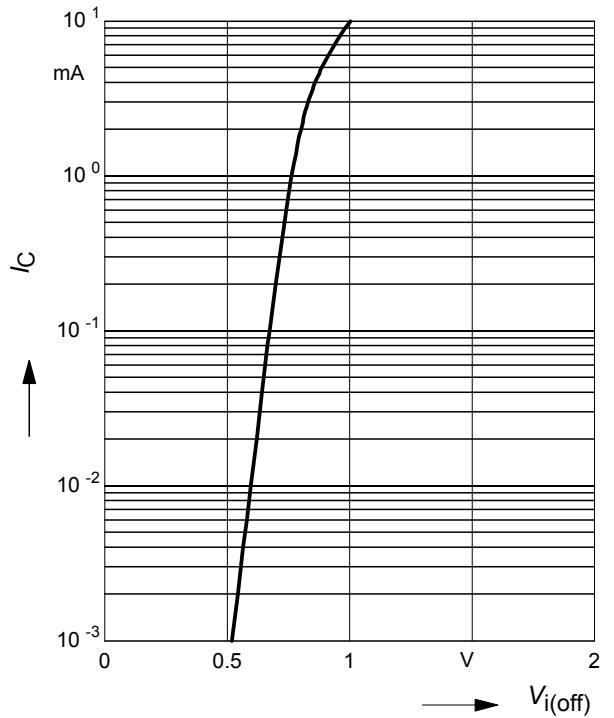
**Input on Voltage**  $V_{i(on)} = f(I_C)$   
 $V_{CE} = 0.3 \text{ V}$  (common emitter configuration)



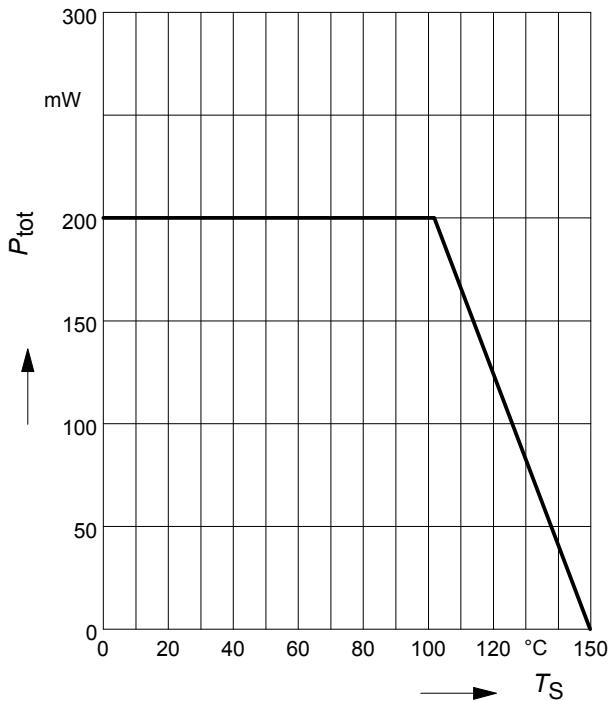
**Collector-emitter saturation voltage**  
 $V_{CEsat} = f(I_C)$ ,  $h_{FE} = 20$



**Input off voltage**  $V_{i(off)} = f(I_C)$   
 $V_{CE} = 5 \text{ V}$  (common emitter configuration)

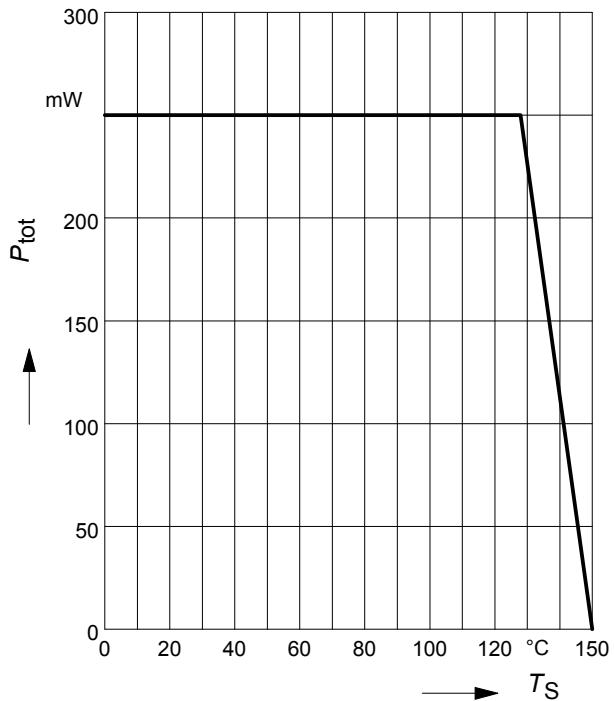


**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
BCR185



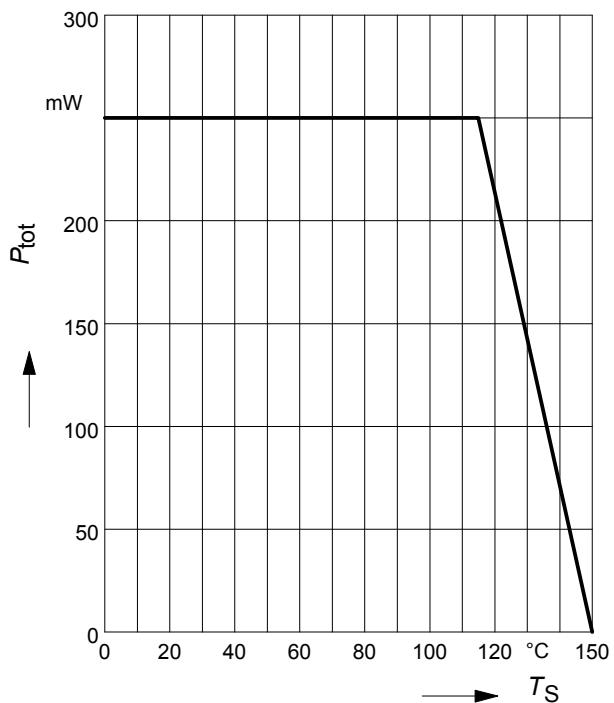
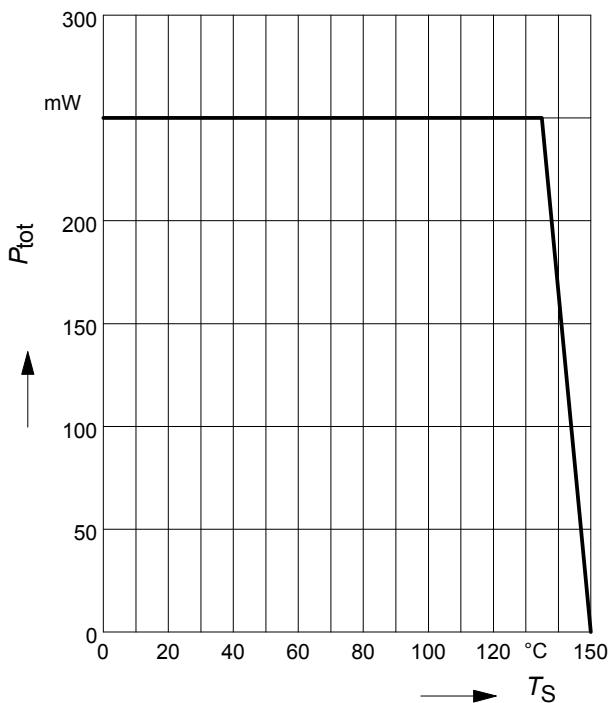
**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
BCR185F

**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
BCR185F

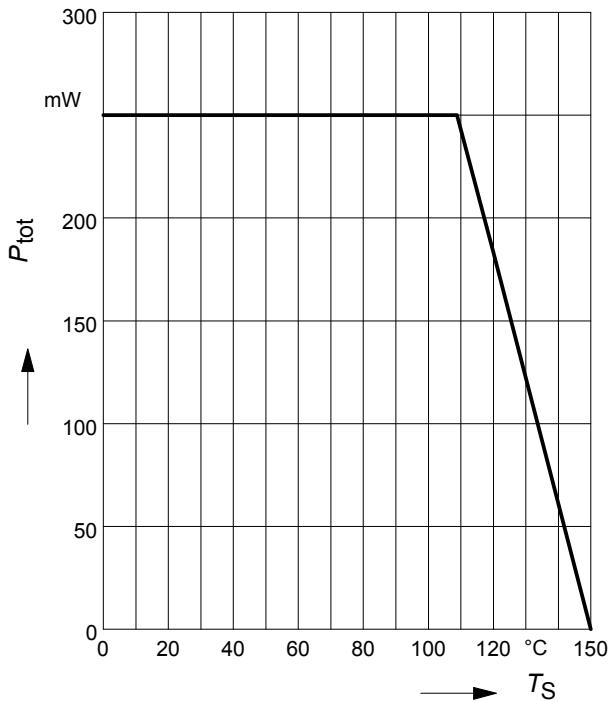


**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
BCR185L3

**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
BCR185S

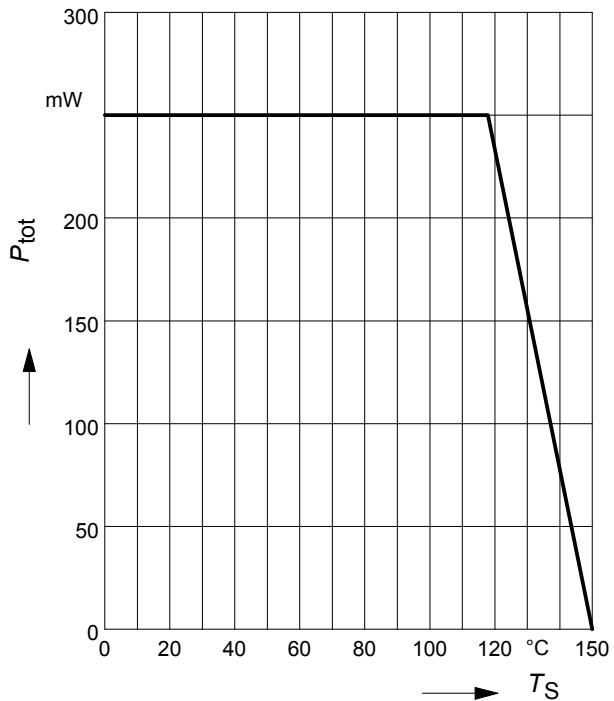


**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
BCR185T

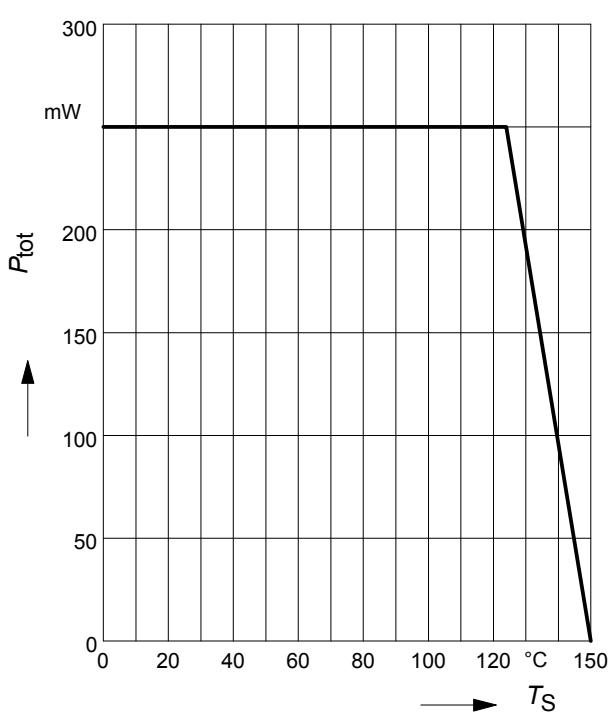


**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
BCR185U

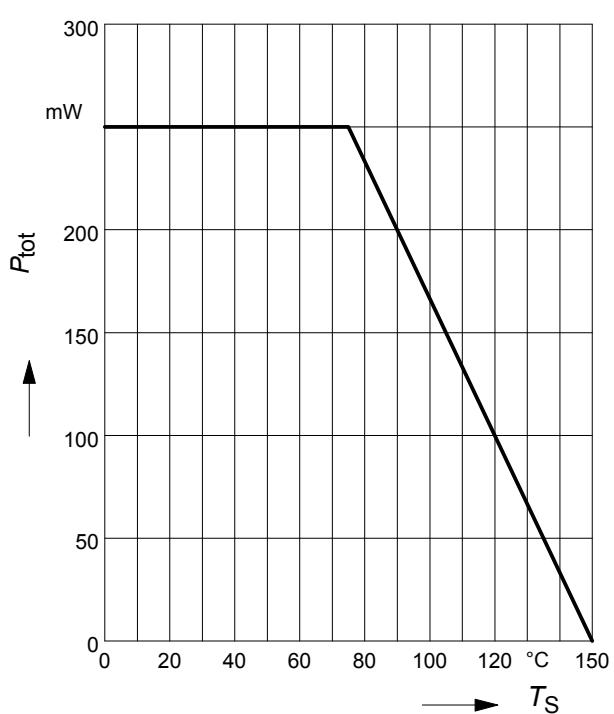
**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
BCR185U



**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
BCR185W

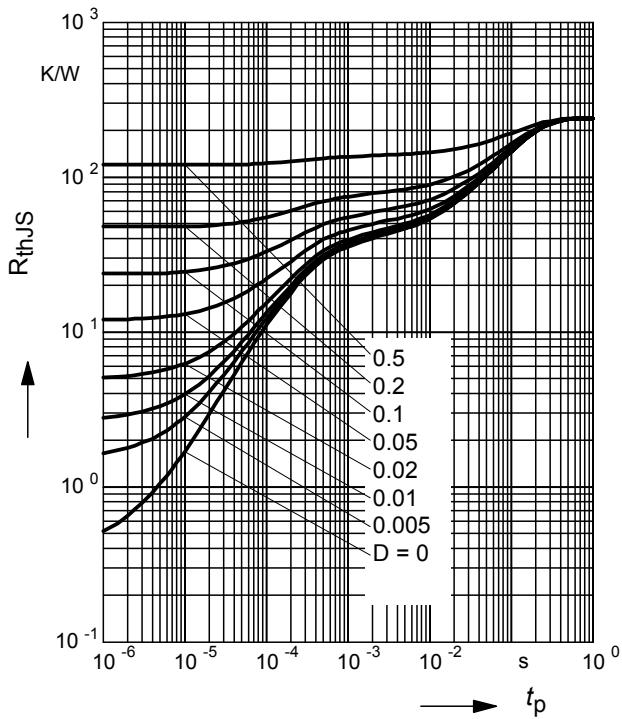


**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
SEMB9



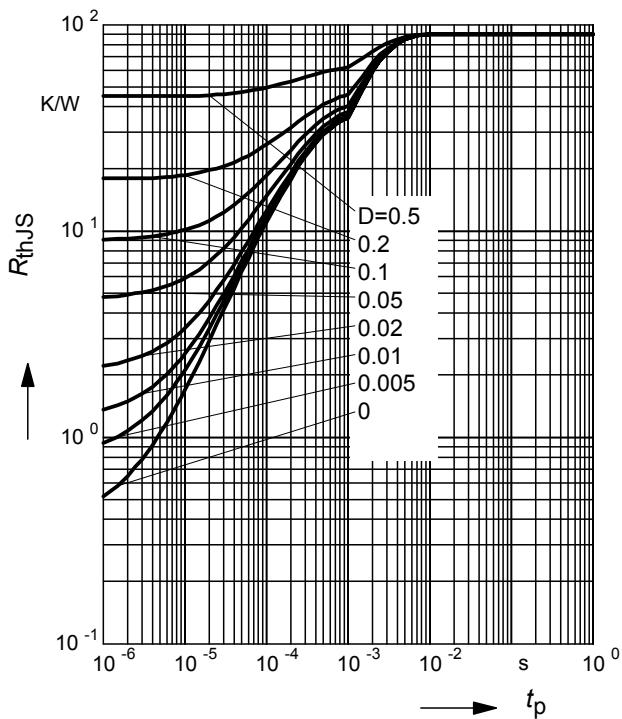
**Permissible Pulse Load**  $R_{\text{thJS}} = f(t_p)$

BCR185



**Permissible Pulse Load**  $R_{\text{thJS}} = f(t_p)$

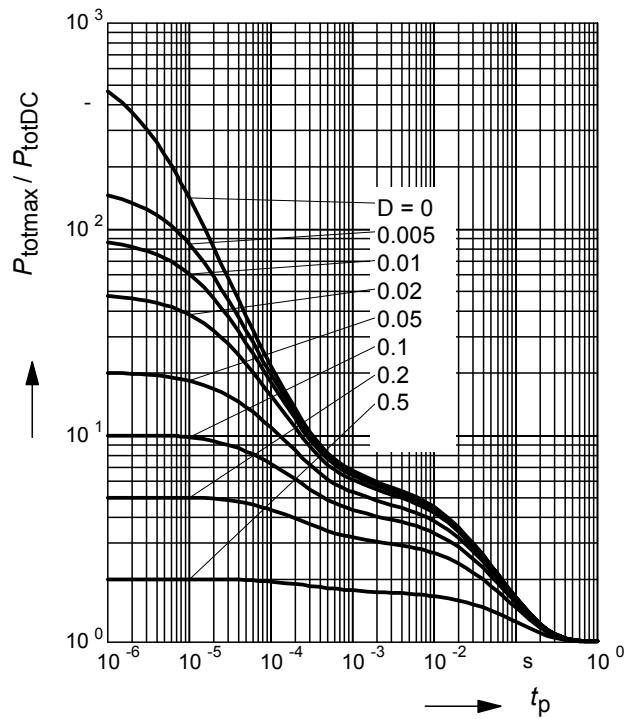
BCR185F



**Permissible Pulse Load**

$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

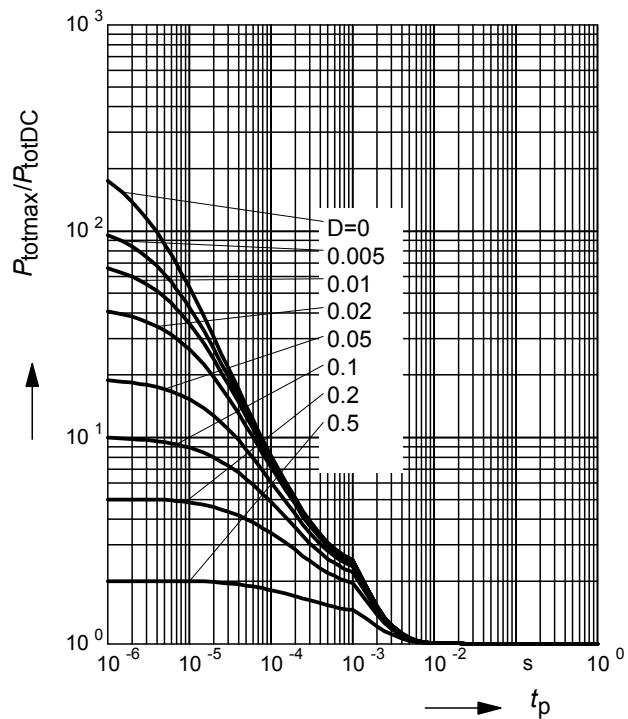
BCR185



**Permissible Pulse Load**

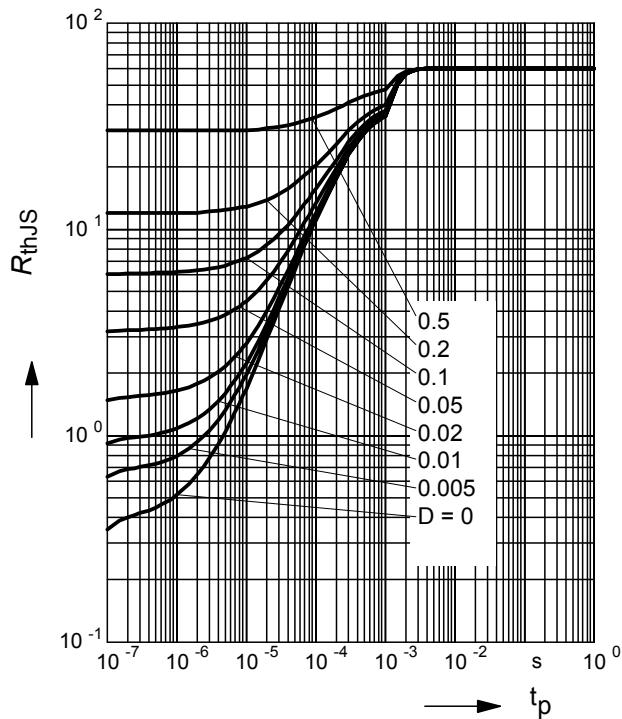
$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

BCR185F



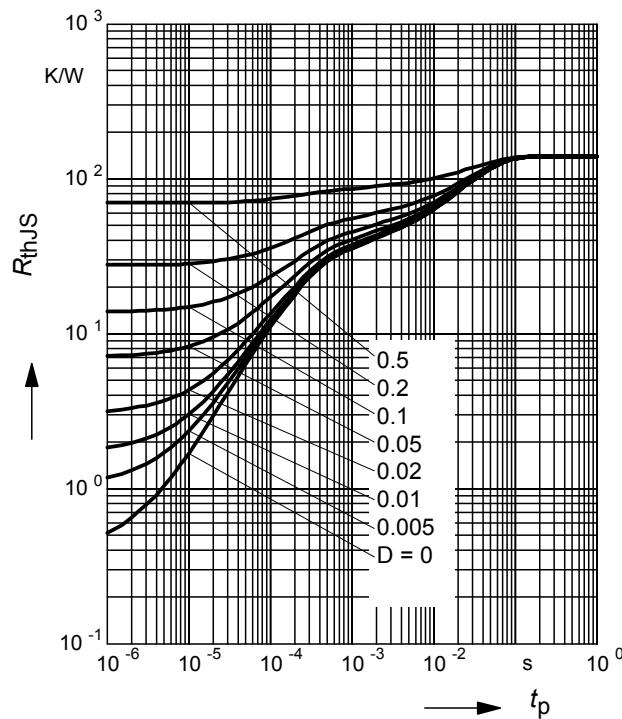
**Permissible Puls Load**  $R_{\text{thJS}} = f(t_p)$

BCR185L3



**Permissible Puls Load**  $R_{\text{thJS}} = f(t_p)$

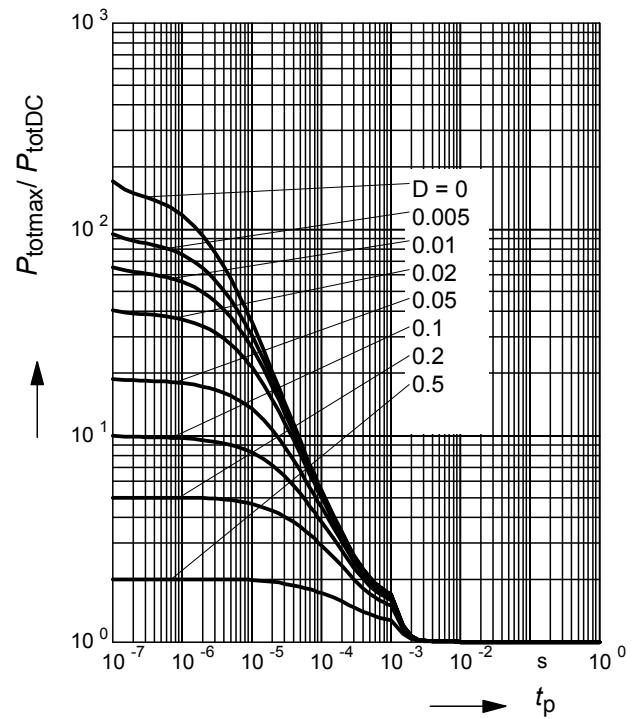
BCR185S



**Permissible Pulse Load**

$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

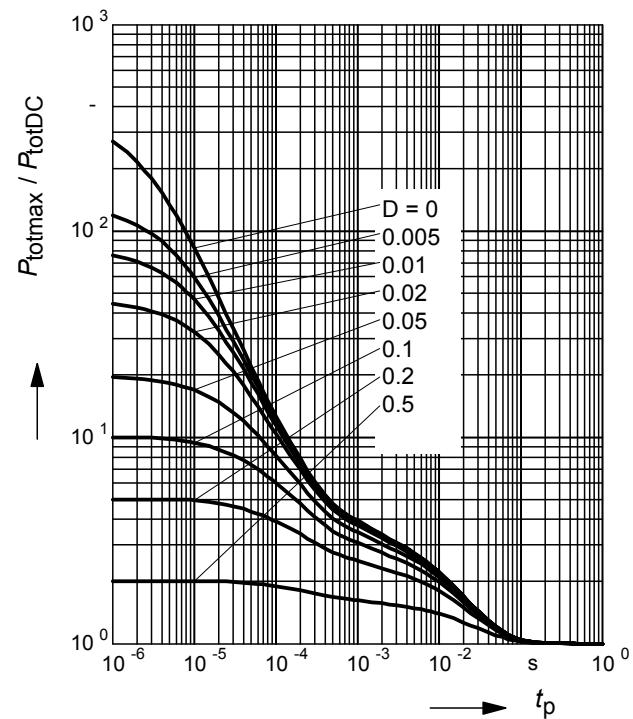
BCR185L3



**Permissible Pulse Load**

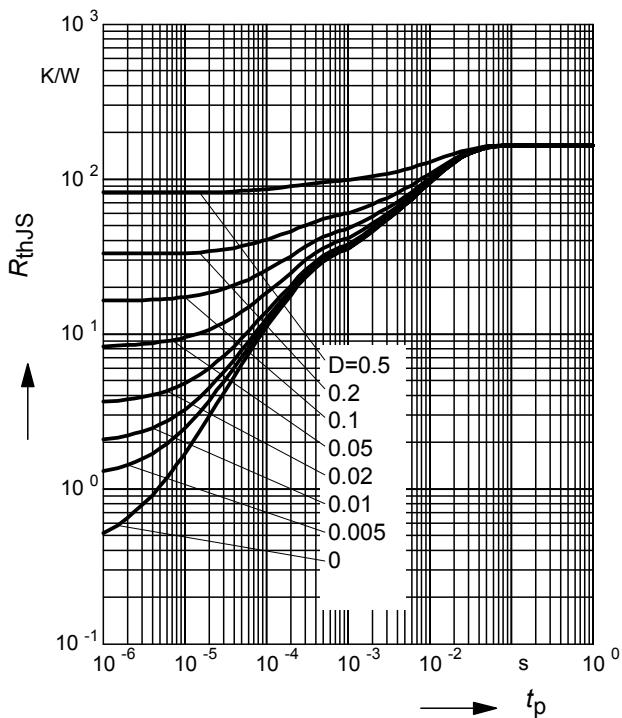
$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

BCR185S



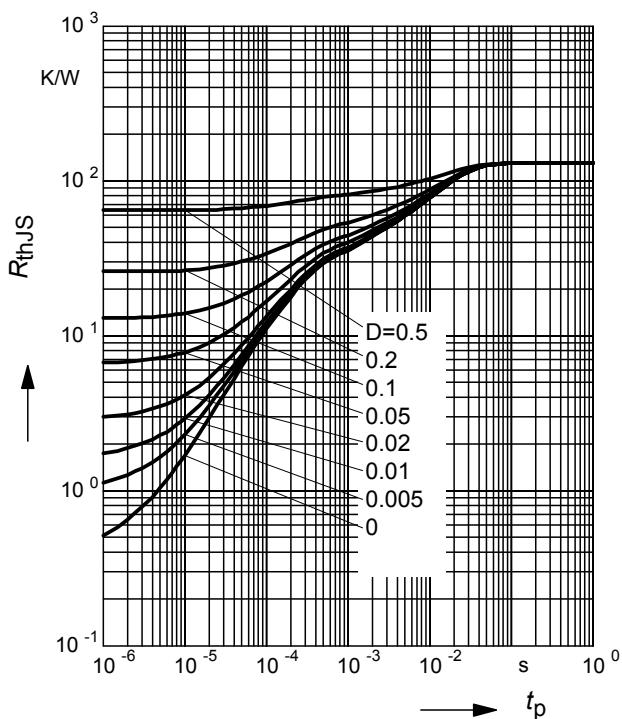
**Permissible Puls Load  $R_{\text{thJS}} = f(t_p)$**

BCR185T



**Permissible Puls Load  $R_{\text{thJS}} = f(t_p)$**

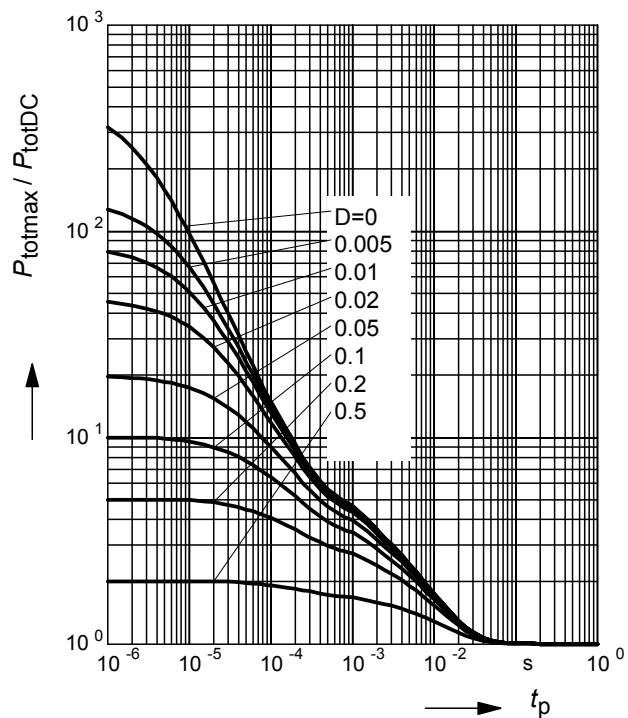
BCR185U



**Permissible Pulse Load**

$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

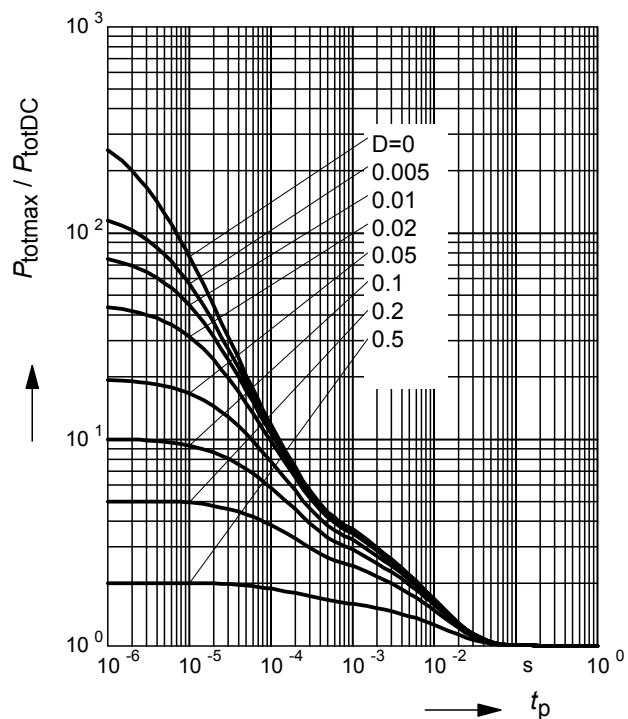
BCR185T



**Permissible Pulse Load**

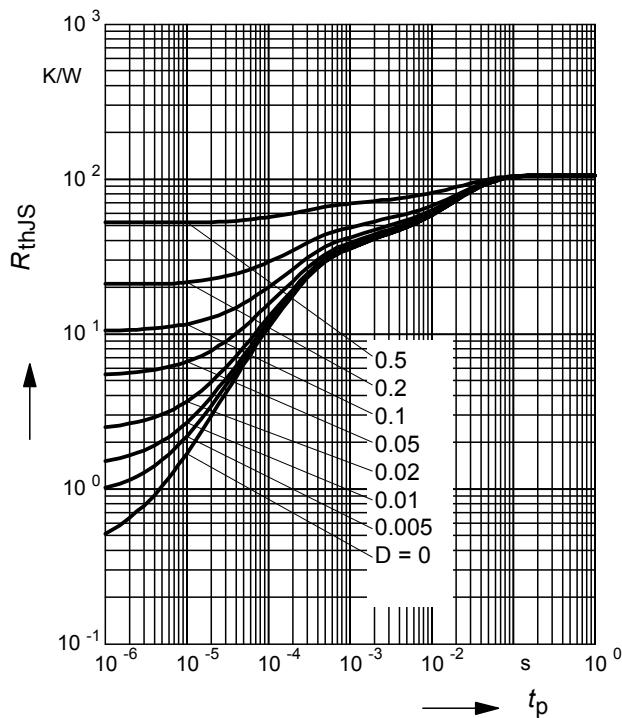
$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

BCR185U

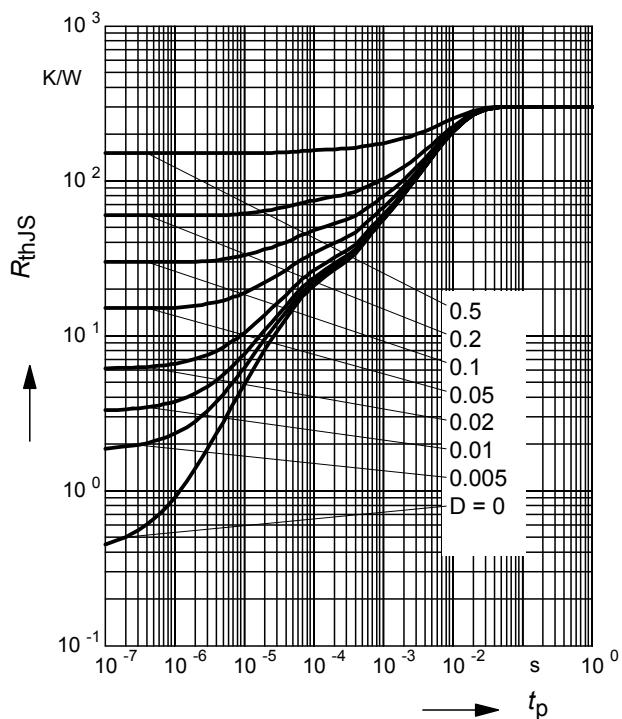


**Permissible Puls Load  $R_{\text{thJS}} = f(t_p)$** 

BCR185W

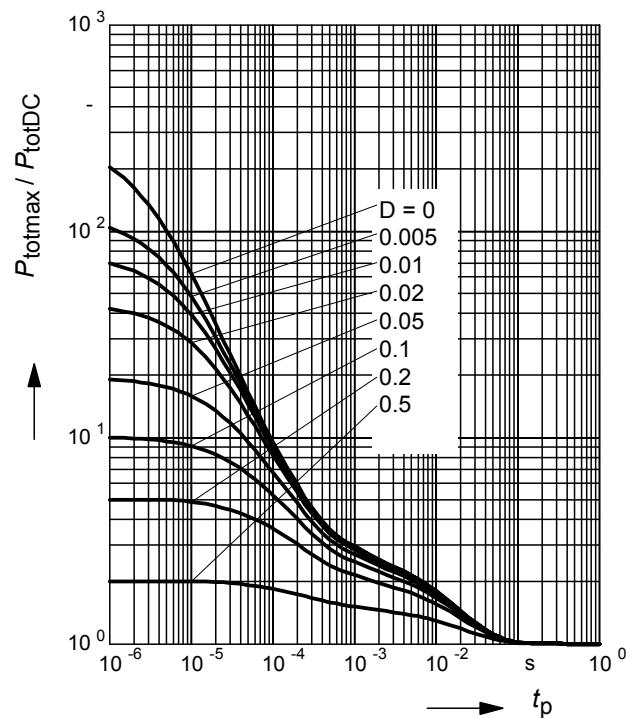

**Permissible Puls Load  $R_{\text{thJS}} = f(t_p)$** 

SEMB9


**Permissible Pulse Load**

$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR185W


**Permissible Pulse Load**

$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

SEMB9

